

# Vishay Semiconductors

# Standard Recovery Diodes, (Stud Version), 12 A



DO-4 (DO-203AA)

PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub> 12 A			
Package DO-4 (DO-203AA)			
Circuit configuration	Single		

#### **FEATURES**

- High surge current capability
- Stud cathode and stud anode version



- Wide current range
- Types up to 1200 V V<sub>RRM</sub>
- · Designed and qualified for industrial and consumer level
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

#### **TYPICAL APPLICATIONS**

- · Battery charges
- Converters
- Power supplies
- · Machine tool controls

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
		12	A	
I <sub>F(AV)</sub>	T <sub>C</sub>	144	°C	
I <sub>F(RMS)</sub>		19	A	
I <sub>FSM</sub>	50 Hz	265	٨	
	60 Hz	280	A	
l <sup>2</sup> t	50 Hz	351	A <sup>2</sup> s	
	60 Hz	320	1 A <sup>c</sup> s	
V <sub>RRM</sub>	Range	100 to 1200	V	
TJ		-65 to +175	°C	

## **ELECTRICAL SPECIFICATIONS**

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V <sub>RRM</sub> , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I <sub>RRM</sub> MAXIMUM AT T <sub>J</sub> = 175 °C mA	
	10	100	150		
	20	200	275		
	40	400	500		
VS-12F(R)	60	600	725	12	
	80	800	950		
	100	1000	1200		
	120	1200	1400		



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FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current	I <sub>F(AV)</sub>	180° conduction, half sine wave		12	А	
at case temperature	'F(AV)	100 Conduc	ziion, nan sine we	100	144	°C
Maximum RMS forward current	I <sub>F(RMS)</sub>				19	Α
		t = 10 ms	No voltage	Sinusoidal half wave,	265	A
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied		280	
non-repetitive surge current	I <sub>FSM</sub>	t = 10 ms	100 % V <sub>RBM</sub>		225	
		t = 8.3 ms	reapplied		235	
	l <sup>2</sup> t	t = 10 ms	No voltage	initial T <sub>J</sub> = T <sub>J</sub> maximum	351	
Maximum 12t for fusing		t = 8.3 ms	reapplied		320	A <sup>2</sup> s
Maximum I <sup>2</sup> t for fusing		t = 10 ms	100 % V <sub>RBM</sub>		250	
		t = 8.3 ms	reapplied		226	
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 to 10 ms, no voltage reapplied		3510	A <sup>2</sup> √s	
Low level value of threshold voltage	V <sub>F(TO)1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum		0.77	V	
High level value of threshold voltage	V <sub>F(TO)2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		0.97	V	
Low level value of forward slope resistance	r <sub>f1</sub>	(16.7 % x $\pi$ x $I_{F(AV)}$ < I < $\pi$ x $I_{F(AV)}$ ), $T_J = T_J$ maximum		10.70	mΩ	
High level value of forward slope resistance	r <sub>f2</sub>	$(I > \pi \times I_{F(AV)}), T_J = T_J \text{ maximum}$		6.20	11122	
Maximum forward voltage drop	$V_{FM}$	I <sub>pk</sub> = 38 A, T <sub>J</sub> = 25 °C, t <sub>p</sub> = 400 μs rectangular wave		1.26	V	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating temperature range	TJ	T <sub>J</sub> -65 to +1 T <sub>Stg</sub> -65 to +2		°C	
Maximum storage temperature range	T <sub>Stg</sub>				
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	R <sub>thJC</sub> DC operation		K/W	
Maximum thermal resistance, case to heatsink	R <sub>thCS</sub>	Mounting surface, smooth, flat and greased	0.5	r√vv	
		Not lubricated threads	1.5 + 0 - 10 %	N⋅m	
Allowable mounting targue			13	lbf ⋅ in	
Allowable mounting torque		Lubricated threads	1.2 + 0 - 10 %	N⋅m	
		Lubricated tilleads	10	lbf ⋅ in	
Approximate weight			7	g	
Approximate weight			0.25	OZ.	
Case style		See dimensions - link at the end of datasheet DO-4 (DO-		-203AA)	

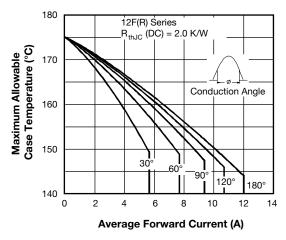
△R <sub>thJC</sub> CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.33	0.26		
120°	0.41	0.44		
90°	0.53	0.58	$T_J = T_J$ maximum	K/W
60°	0.78	0.81		
30°	1.28	1.29		

#### Note

• The table above shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC



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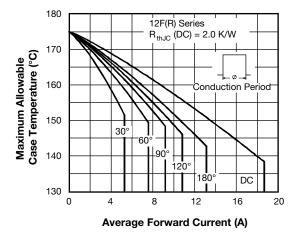


Fig. 1 - Current Ratings Characteristics

Fig. 2 - Current Ratings Characteristics

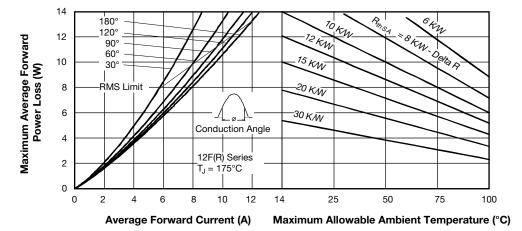


Fig. 3 - Forward Power Loss Characteristics

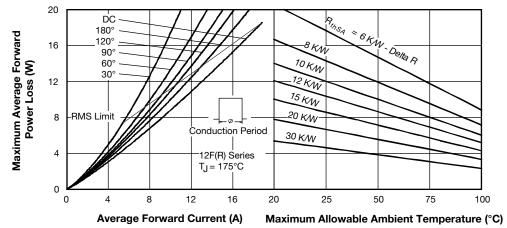


Fig. 4 - Forward Power Loss Characteristics

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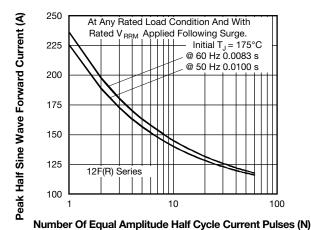
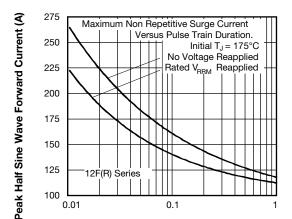


Fig. 5 - Maximum Non-Repetitive Surge Current



Pulse Train Duration (s)
Fig. 6 - Maximum Non-Repetitive Surge Current

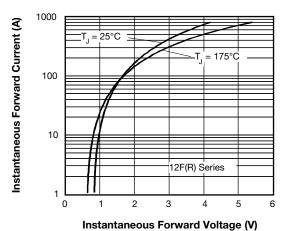


Fig. 7 - Forward Voltage Drop Characteristics

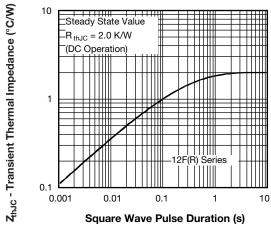
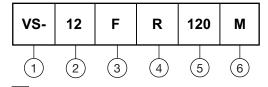


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

### **ORDERING INFORMATION TABLE**

## Device code



- 1 Vishay Semiconductors product
- 2 Current rating: code = I<sub>F(AV)</sub>
- 3 F = standard device
- 4 None = stud normal polarity (cathode to stud)

R = stud reverse polarity (anode to stud)

- 5 Voltage code x 10 = V<sub>RRM</sub> (see Voltage Ratings table)
- 6 None = stud base DO-4 (DO-203AA) 10-32UNF-2A

M = stud base DO-4 (DO-203AA) M5 x 0.8

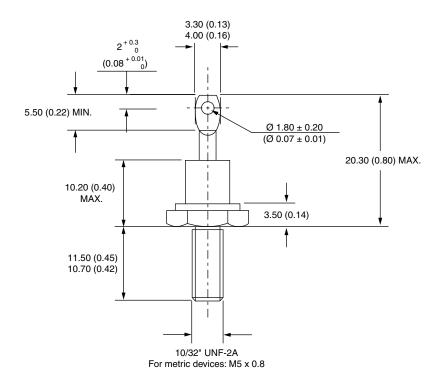
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95311	

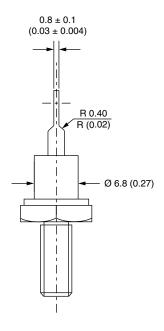


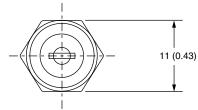
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# DO-203AA (DO-4)

## **DIMENSIONS** in millimeters (inches)









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